TOSHIBA

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

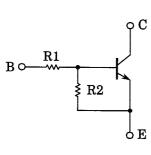
# RN1961,RN1962,RN1963 RN1964,RN1965,RN1966

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

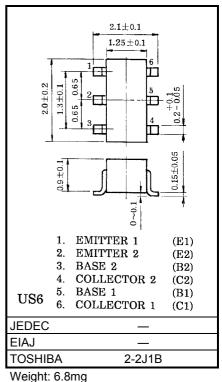
- Including two devices in US6 (ultra super mini type 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2961~RN2966

### **Equivalent Circuit and Bias Resistor Values**

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

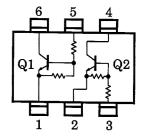


Type No.	R1 (kΩ)	R2 (kΩ)			
RN1961	4.7	4.7			
RN1962	10	10			
RN1963	22	22			
RN1964	47	47			
RN1965	2.2	47			
RN1966	4.7	47			



# **Equivalent Circuit (Top View)**

#### Characteristic Symbol Rating Unit Collector-base voltage 50 ٧ **V**CBO RN1961~1966 Collector-emitter voltage 50 V VCEO RN1961~1964 10 Emitter-base voltage VEBO V RN1965, 1966 5 Collector current 100 Ic mΑ Collector power dissipation $P_{C}^{*}$ 200 mW RN1961~1966 Junction temperature °C Тj 150 Storage temperature range -55~150 °C Tstg



\*: Total rating

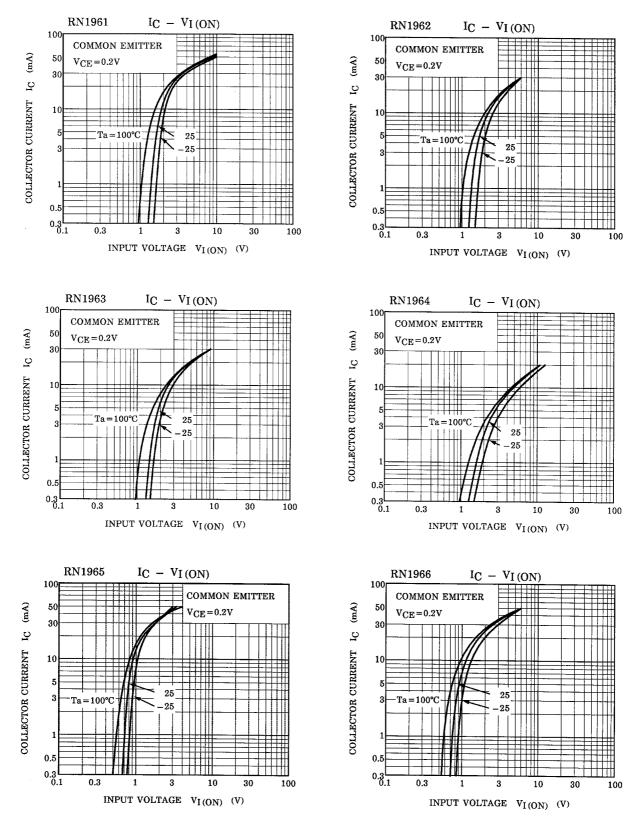
Unit: mm

# Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteris	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	RN1961~1966	I <sub>CBO</sub>	-	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	—	_	100	nA
Collector cut-on current		I <sub>CEO</sub>	_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	
	RN1961	IEBO	_	- V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	- mA
	RN1962		_		0.38	_	0.71	
Funither out off ourset	RN1963		_		0.17	-	0.33	
Emitter cut-off current	RN1964		_		0.082	_	0.15	
	RN1965		_	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1966		_		0.074	_	0.138	
	RN1961	h <sub>FE</sub>	—	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	30	_	—	· ·
	RN1962		_		50	_	—	
	RN1963		_		70	_	_	
DC current gain	RN1964		_		80	_	_	
	RN1965		_		80	_	_	
	RN1966		_		80	_	_	
Collector-emitter saturation voltage	RN1961~1966	V <sub>CE (sat)</sub>	-	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
	RN1961	Vi (on)	-	- V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	V
	RN1962		_		1.2	_	2.4	
	RN1963		_		1.3	_	3.0	
Input voltage (ON)	RN1964		_		1.5	_	5.0	
	RN1965		_		0.6	_	1.1	
	RN1966		_		0.7	_	1.3	
	RN1961~1964	V <sub>I (OFF)</sub>	—	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	v
Input voltage (OFF)	RN1965, 1966		_		0.5	_	0.8	
Translation frequency	RN1961~1966	f <sub>T</sub>	—	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	—	MHz
Collector output capacitance	RN1961~1966	C <sub>ob</sub>	-	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	-	3	6	pF
	RN1961	R1	_	-	3.29	4.7	6.11	- - kΩ
	RN1962		_		7	10	13	
	RN1963		_		15.4	22	28.6	
Input resistor	RN1964		_		32.9	47	61.1	
	RN1965		_		1.54	2.2	2.86	
	RN1966		_	1	3.29	4.7	6.11	
	RN1961~1965	R1/R2	-		0.9	1.0	1.1	
Resistor ratio	RN1965		_		0.0421	0.0468	0.0515	
	RN1966		_		0.09	0.1	0.11	

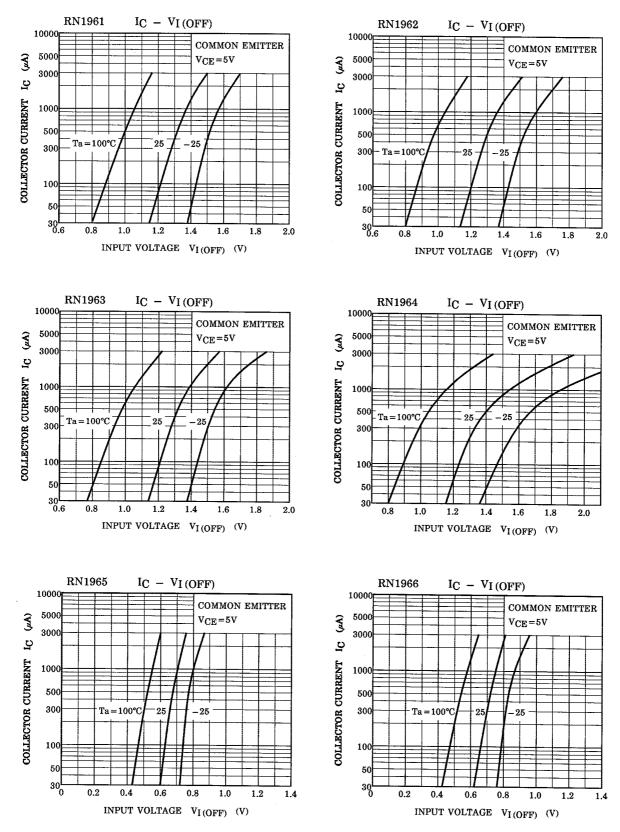
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### (Q1, Q2 Common)

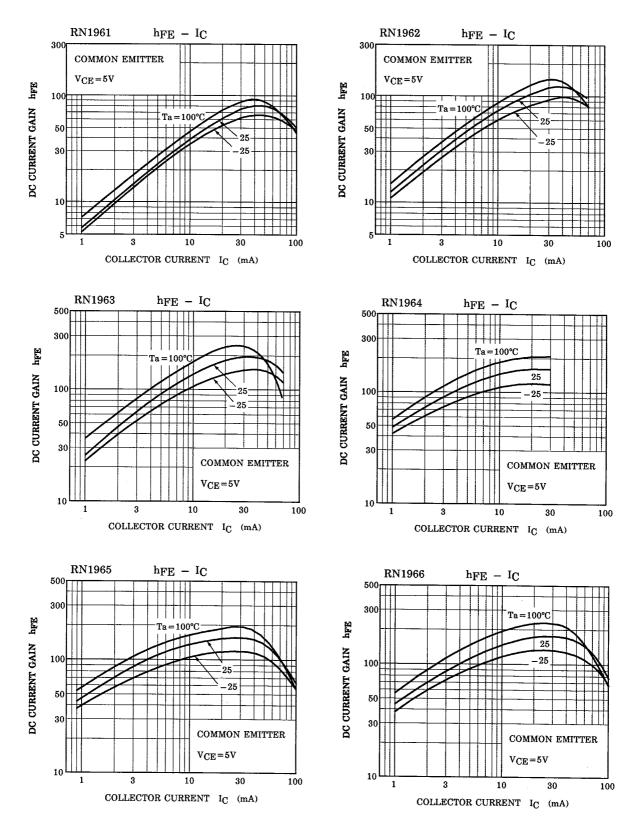


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### (Q1, Q2 Common)



(Q1, Q2 Common)



Type Name	Marking		
RN1961	Type Name XXA UUU		
RN1962	Type Name X X B HEE		
RN1963	Type Name XXC UUU		
RN1964	Type Name XXD HEE		
RN1965	Type Name XXE BBB		
RN1966	Type Name XXF UTT		

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